



# Elucidating facet dependent electronic and electrochemical properties of Cu<sub>2</sub>O nanocrystals using AFM/SCM and DFT

Qingquan Ma<sup>a</sup>, Joshua Young<sup>b</sup>, Sagnik Basuray<sup>b</sup>, Guangming Cheng<sup>c</sup>, Jianan Gao<sup>a</sup>, Nan Yao<sup>c</sup>, Wen Zhang<sup>a,b,\*</sup>

<sup>a</sup> John A. Reif, Jr. Department of Civil and Environmental Engineering, New Jersey Institute of Technology, Newark, NJ 07102, United States

<sup>b</sup> Otto H. York Department of Chemical and Materials Engineering, New Jersey Institute of Technology, Newark, NJ 07102, United States

<sup>c</sup> Princeton Institute for the Science and Technology of Materials, Princeton University, Princeton, NJ 08544, United States

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## ABSTRACT

Cuprous oxide (Cu<sub>2</sub>O) has extensively been studied owing to its excellent optical, magnetic, and catalytic properties. Many of these properties are facet-dependent and have not been well elucidated. This work synthesized cubic, cuboctahedral, octahedral, and rhombic dodecahedral shaped Cu<sub>2</sub>O nanocrystals of ~300 nm in size to evaluate the facet-dependent electrochemical activities. Cyclic voltammetry (CV) and electrochemical impedance spectroscopy (EIS) were firstly used to reveal the average electrochemical activities at the ensemble level. Atomic force microscopy-scanning electrochemical microscopy (AFM-SECM) was further used to assess the electrochemical activities of different Cu<sub>2</sub>O nanocrystals at the facet level. Hexaammineruthenium (III) chloride ([Ru(NH<sub>3</sub>)<sub>6</sub>]Cl<sub>3</sub>) was employed as the probe molecules that reacted with four different Cu<sub>2</sub>O nanocrystals under -400 mV and yielded ~300 pA current between the probing tip and the nanocrystal surface. The tip-current mapping results indicate that rhombic dodecahedral Cu<sub>2</sub>O exhibits higher electrocatalytic activity than other shaped Cu<sub>2</sub>O, due to the presence of dominant exposed facet of {110} as indicated by the relatively high tip current. Density-functional theory (DFT) calculations confirmed the facet dependence of local surface energy and electronic structure of Cu<sub>2</sub>O nanocrystals. Besides electrochemical activity, the surface work function and adsorptive properties were both observed to vary with the shape and dominant exposed facets of Cu<sub>2</sub>O. This study presented a unique experimental and computational chemistry approach to analyze surface electrochemical properties of Cu<sub>2</sub>O crystals at a crystalline facet level.

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## Introduction

It is commonly known that the smaller nanoparticle size becomes, the larger their surface area, resulting in greater reactivity or other surface properties. However, recent studies demonstrated that a smaller size does not necessarily correlate with reactivity, suggesting that other aspects such as the exposed crystal surfaces or facets begin to govern the nanoparticle reactivity at nanoscale.[1] For instance, many metal-oxide nanoparticles such as Cu<sub>2</sub>O and Ag<sub>2</sub>O in cubic, cuboctahedral, octahedral, and rhombic dodecahedral shapes elicit facet-dependent catalytic, photocatalytic, and molecular adsorption properties.[2,3] For example, Amanda et al. discovered that the adsorption of selenium oxyanions onto the {110}

hematite facets was higher than that of {012} using extended X-ray absorption fine edge spectroscopy (EXAFS).[4] Chen et al. demonstrated that {111} facets of Pt or Pd NPs are significantly more active than {001} facets toward carbon monoxide (CO) oxidation using diffuse reflectance infrared Fourier transform spectroscopy (DRIFTS).[5] Wu et al. reported that the water-splitting reactions on CeO<sub>2</sub> {110} and {111} facets are 10 ~ 100 times faster than that on CeO<sub>2</sub> {100} facet at temperature (T) < 950 K using DFT simulations.[6] Huang et al. reported that the band structures, electrical conductivities and photocatalytic activities of facet-specific Cu<sub>2</sub>O cube, octahedron, and rhombic dodecahedron are highly related to their exposure facets.[7–9] For example, the {100} facet of Cu<sub>2</sub>O has a fixed band gap of 1.787 eV, while {110} and {111} yielded an oscillating band gap between 0 and 1.787 eV. Moreover, the {111}-octahedron is highly conductive, whereas the {110}-rhombic dodecahedron is insulating and the {100} facet is moderately conductive. Finally, the photocatalytic activities of Cu<sub>2</sub>O follow the order

\* Corresponding author at: John A. Reif, Jr. Department of Civil and Environmental Engineering, New Jersey Institute of Technology, Newark, NJ 07102, United States.

E-mail address: [wenzhang@njit.edu](mailto:wenzhang@njit.edu) (W. Zhang).

of {110}-rhombic dodecahedron > {111}-octahedron > {100}-cube. Furthermore, control of surface termination on  $\text{TiO}_2$  nanoparticles can enhance the electrochemical reaction selectivity and suppress the competing reaction pathways or byproduct interference.[10,11] Peng et al. examined the electronic states and structures of  $\text{TiO}_2$  on particular facets such as {001} and {101} using  $^{31}\text{P}$  nuclear magnetic resonance (NMR) in combination with trimethylphosphine (TMP) as a surface probe. They found that surface Ti cations on various facets with different Lewis acidities, surface energies, and steric arrangements are different.[12].

Characterizing the influences of surface crystal facets on their properties at the nanoscale or atomic scale still remains challenging, because many surface characterization techniques such as Raman mapping, electrochemical measurements, surface plasmon resonance, and fluorescence microscopy usually resolve the average information of surface properties or at the single nanoparticle level. Only a few techniques such as XAFS, NMR, DRIFTS, and liquid cell (high-resolution) transmission electron microscopy (LTEM) were demonstrated to detect facet-level material properties.[13–15] For example, Sung et al. reported the different etching redox behavior of {100} for reduction and {111} for oxidation of ceria-based nanocrystals under the control of redox-governing factors using LTEM.[16] By contrast, traditional electrochemical measurements, such as cyclic voltammetry (CV), linear sweep voltammetry (LSV), and electrochemical impedance spectroscopy (EIS), only resolves average surface information of bulk materials or aggregated nanoparticles.[17,18] Interpretation of macroscale electrochemical measurement results may be affected by nanoparticle aggregation states or surface coverage of nanoparticles on the electrode surface. Similarly, scanning electrochemistry microscopy (SECM) employs microelectrode probes that thus achieves a micrometer resolution. For nanoscale characterization, atomic force microscopy-scanning electrochemical microscopy (AFM-SECM) has increasingly been used in simultaneously probing morphology and electrochemically active sites of various nanomaterials, such as dimensionally stable anodes,[19] noble metal nanoparticles,[20] functionalized electrodes,[21] and soft electronic devices.[22] For example, mediator-tethered AFM-SECM successfully reveals the local electrochemical activity of 20-nm gold nanoparticles/nanodots functionalized by redox-labeled PEG chains deposited on gold surface.[20] Catalytic current mapping of oxygen reduction reaction or hydrogen peroxide generation on individual 300-nm Pt particles was achieved by AFM-SECM.[23,24] Thus, the catalytic particles' surface activity under activation controlled and diffusion controlled electrochemical reaction conditions could be measured.

This study employed AFM-SECM to examine the facet/shape-dependent electrochemical properties of individual cuprous oxide ( $\text{Cu}_2\text{O}$ ) nanocrystals of four shapes: nanocubes with the dominant {100} facet, rhombic dodecahedrons with the dominant {110} facet, octahedrons with the dominant {111} facet, and cuboctahedrons with {111} and {100} facets.  $\text{Cu}_2\text{O}$  is a p-type semiconductor with a direct band gap of about 2.17 eV,[25] which emerges as a promising material in photocatalysis,[26] catalysis,[27] antibacterial activity,[28] gas sensor,[29,30] supercapacitors,[31] lithium-ion batteries,[32] ion detection,[33] surface-enhanced Raman scattering (SERS),[34] organocatalysis,[35] and photoelectrochemical water splitting.[36] Here, we performed AFM-SECM mapping on cuprous oxide ( $\text{Cu}_2\text{O}$ ) nanoparticles with different shapes or exposed facets. To support the facet-dependent electrochemical analysis, kelvin probe force microscopy (KPFM) was also conducted to measure the local work function of the different facets. Finally, density functional theory (DFT) simulations were performed to assess the electron transfer at the interface of different cuprous oxide ( $\text{Cu}_2\text{O}$ ) nanocrystals and interpret the facet-dependent electrochemical properties.

## Materials and methods

### Preparation of cuprous oxide ( $\text{Cu}_2\text{O}$ ) nanoparticles with different exposed facets

Copper (II) chloride dihydrate ( $\text{CuCl}_2 \cdot 2\text{H}_2\text{O}$ ), Sodium hydroxide, Sodium dodecyl sulfate (SDS), and hydroxylamine hydrochloride ( $\text{NH}_2\text{OH} \cdot \text{HCl}$ ) were purchased from Fisher Scientific. Deionized water was used to prepare all solutions which is produced from a Milli-Q water machine (Direct-Q 3UV, Millipore) that produces ultrapure deionized water with resistivity of 18.2  $\text{M}\Omega \cdot \text{cm}$  at 25 °C. To avoid the effect of the surface-capping ligands on catalytic activities, we synthesized the different shaped nanocrystals with the same coating molecule of SDS using the seed-mediated approaches.[33] Cube, cuboctahedron, octahedron and rhombic dodecahedron shapes formed due to the increasing of the volumes of  $\text{NH}_2\text{OH}_3 \cdot \text{HCl}$  that change the amount of reductant added.[33]  $\text{Cu}_2\text{O}$  nanocrystals with cubic and rhombic dodecahedral structures were synthesized by adding precisely 9.55 mL, 9.35 mL, 9.05 mL, and 8.75 mL of deionized water respectively to four sample vials labeled a, b, c, and d, which were placed in a water bath at 32–34 °C. Then, 0.1 mL of a 0.1-M  $\text{CuCl}_2$  solution and 0.087 g of SDS powder were added to each vial with vigorous stirring. After complete dissolution of the SDS powder, 0.20 mL of a 1.0-M NaOH solution was added, which turned the solution color into light blue immediately, due to the formation of  $\text{Cu}(\text{OH})_2$  precipitate. Finally, 0.15, 0.35, 0.65, and 0.95 mL of 0.2 M  $\text{NH}_2\text{OH}_3 \cdot \text{HCl}$  were quickly spiked within 5 s into vials a, b, c, and d, respectively. The total solution volume in each vial was now 10 mL. After the vials were stirred for 20 s, they were kept in the water bath at 37 °C for 2 h for nanocrystal growth. The suspension was centrifuged at 4000  $\times g$  for 5 min. After the supernatant was decanted, the precipitate was washed with 6 mL of a 1:1 vol ratio of water and ethanol. The precipitate was centrifuged and washed again using the same water/ethanol mixture to remove unreacted chemicals and SDS. The final washing step used 5 mL of ethanol, and the precipitate was dispersed in 0.6 mL of ethanol for storage and analysis.

### Morphology and Facet Indexing for different shaped $\text{Cu}_2\text{O}$

Scanning electron microscopy (SEM) images for four kinds of nanocrystal samples were taken by a field emission scanning electron microscope (FE-SEM) (JSM-7900 F, JEOL). Further facet identification and individual facet surface areas were determined statistically by a Verios 460 e Extreme High-Resolution Scanning Electron Microscope (XHR-SEM). At least 50 single nanocrystal particles of one kind were selected for XHR-SEM imaging. Titan Cubed Themis 300 double Cs-corrected Scanning/Transmission Electron Microscope (S/TEM) were operated to obtain the selected-area electron diffraction (SAED) patterns for facet identification. An X-ray diffraction (XRD, Philips, EMPYREAN, PANalytical Almelo, The Netherlands) equipped with a  $\text{Co K}\alpha$  radiation source measured the crystalline structure of the  $\text{Cu}_2\text{O}$  nanocrystals.

### Facet-level analysis of surface properties

#### Work function determination by kelvin probe force microscopy (KPFM)

Work function is a direct consequence of the electrostatic barrier induced by the dipole double layer at the surface.[37] KPFM was used to obtain surface potential mapping on the  $\text{Cu}_2\text{O}$  nanocrystals to reveal the facet dependent surface electronic properties. The measured surface potential is the contact potential difference (CPD) due to the difference in work functions (or Fermi energy levels) between the sample surface and the tip. Surface work function is affected by surface charges, doping levels, defects or grain boundaries. KPFM was operated on a Bruker Dimension Icon® with the Frequency modulation KPFM integrated with PeakForce Tapping

mode. Briefly, Platinum-Iridium (Pt/Ir) doped silicon cantilever probes (Bruker, USA) were used as the conductive probes that have a relative stable work function ( $\Phi_{\text{tip}}$ ), [38] a force constant of approximately  $3 \text{ N}\cdot\text{m}^{-1}$  and a nominal resonance frequency of 75 kHz.  $\text{Cu}_2\text{O}$  nanocrystals were immobilized on Silicon wafers ( $\varnothing 3''$  Silicon wafer, Type P/ $<111$ , TED PELLA, Inc.) by depositing  $5 \mu\text{L}$  of the  $\text{Cu}_2\text{O}$  suspensions ( $10 \text{ mg}\cdot\text{L}^{-1}$ ) with  $\sim 30$  min vacuum drying. During the operation, the microscope was fully contained in an environmental chamber with temperature ( $25 \pm 2^\circ\text{C}$ ) and humidity ( $< 10\%$ ). The sample surface's work function ( $\Phi_{\text{sample}}$ ) was calculated by  $\text{CPD} = -(\Phi_{\text{tip}} - \Phi_{\text{sample}})/e$ . To determine the work function of the tip ( $\Phi_{\text{tip}}$ ), we utilized three reference substrates, Au {111} substrate, highly oriented pyrolytic graphite (HOPG) and Si {111} substrates, which have stable work functions of 5.20–5.60 eV, 4.4–4.8 eV and 4.60–4.85 eV respectively. Each cantilever tip we used went through the same calibration process to determine the individual work function. At least 50 different facet regions of each shape on the deposited sample were probed to achieve statistical significance of the CPD measurement. More details about KPFM's tip calibration are provided in the section S1 in the [supporting information](#).

#### Surface electrochemical activity measurement by AFM/SECM

Besides KPFM,  $\text{Cu}_2\text{O}$  nanocrystals were also scanned for local surface electrochemical properties by the same Bruker AFM that was connected with a standard PeakForce SECM as introduced previously. [39] Prior to the PeakForce SECM measurement, all PeakForce SECM probes (Bruker Nano Inc, CA, US) were tested by performing cyclic voltammetry in a standard three-electrode electrochemical cell with a Pt counter electrode and a standard Ag/AgCl reference electrode. The electrochemical cell was filled with 1.8 mL of 10 mM  $[\text{Ru}(\text{NH}_3)_6]\text{Cl}_3$  (one of commonly used redox couples for aqueous electrolytes to simulate fictive species reactions) in 0.1 M KCl. A bipotentiostat (CHI700E, CH Instrument) was connected to the electrochemical cell to perform the cyclic voltammetry analyses with a scanning voltage from 0 to  $-0.4 \text{ V}$  vs. Ag/AgCl at  $50 \text{ mV}\cdot\text{s}^{-1}$  applied to the SECM probes. Both the probe and the sample on the substrate were working electrodes sharing the same reference and counter electrodes. The probe and the sample were biased at different potentials, relative to the reference electrode, to enable different chemical reactions. In this work, the probe reduces the  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  to  $[\text{Ru}(\text{NH}_3)_6]^{2+}$  at  $-400 \text{ mV}$  versus a pseudo Ag/AgCl reference electrode, while the sample is biased at  $+100 \text{ mV}$  to oxidize  $[\text{Ru}(\text{NH}_3)_6]^{2+}$  back to  $[\text{Ru}(\text{NH}_3)_6]^{3+}$ . We hypothesize that different dominant facets of  $\text{Cu}_2\text{O}$  should generate different levels of tip-sample currents at a sensitivity of  $\text{nA}\cdot\text{V}^{-1}$  due to the reactivity differences and thus generate imaging contrast from the background or the silicon substrate that had negligible electrochemical oxidation reactions with  $[\text{Ru}(\text{NH}_3)_6]^{3+}$ . The PeakForce SECM scan was performed using an interleaved scan mode with a lift height of typically 40–150 nm between the probe and the sample surface. On each line scan during the main scan, the probe scans over the sample surface using the normal PeakForce QNM mode at a scan rate at 0.1 Hz and a scan size at  $2 \times 2 \mu\text{m}$ . After verifying SECM standard test sample (silicon nitride pattern cover on Pt layer) the sample-coated substrate was placed into the same fluidic cell to replace the SECM standard test sample. The same SECM scanning procedure was performed on the sample surface at a DC bias of  $-400 \text{ mV}$  and  $+100 \text{ mV}$  applied to the probe and the sample substrate at the scan rate of 0.1 Hz and a scan size is  $2 \times 2 \mu\text{m}$ .

#### DFT calculations of surface properties

The Vienna Ab Initio Simulation Package (VASP) was used to perform all the density functional theory (DFT) calculations within the generalized gradient approximation (GGA) using the Perdew-Burke-Ernzerhof (PBE) formulation. [40,41] We employed projected

augmented wave (PAW) potentials to describe the ionic cores and took valence electrons into account using a plane wave basis set with a kinetic energy cutoff of 500 eV. [42,43] Partial occupancies of the Kohn-Sham orbitals were allowed using the Gaussian smearing method with a width of 0.05 eV. The electronic energy was considered self-consistent when the energy change was smaller than  $10^{-6} \text{ eV}$ . A geometry optimization was considered convergent when the force change was smaller than  $0.02 \text{ eV}\cdot\text{\AA}^{-1}$ . Grimme's DFT-D3 methodology was used to describe the dispersion interactions. [44].

The equilibrium lattice constants and atomic positions of a  $\text{Cu}_2\text{O}$  unit cell in the cubic  $Pm\bar{3}m$  space group were optimized using a  $6 \times 6 \times 6$  Monkhorst-Pack k-point grid for Brillouin zone sampling. The {100}, {110} and {111} surfaces of  $\text{Cu}_2\text{O}$  were constructed with  $p$  ( $2 \times 2 \times 2$ ) periodicity in the x, y and the z direction separated by a vacuum layer in the depth of 15 Å in order to separate the surface slab from its periodic duplicates. During structural optimizations, the  $\Gamma$  point in the Brillouin zone was used for k-point sampling.

The surface energy ( $\gamma_r$ ) of  $\text{Cu}_2\text{O}$  facets can be described as: [37].

$$\gamma_r = \frac{(G_{\text{surf}} - \sum_i N_i \mu_i)}{A}, \quad (1)$$

where  $G_{\text{surf}}$  is the Gibbs free energy of the surface (eV),  $\mu_i$  is the chemical potential of each species (eV) (in this case  $i = \text{Cu}$  and  $\text{O}$ ),  $A$  is the surface area ( $\text{m}^2$ ), and  $N_i$  represents the number of each species that the surface contains [45].

The work function was calculated by Eq. (2) to compare with the experimental data from KPFM using the equation.

$$\Phi = E_{\text{vac}} - E_f \quad (2)$$

where  $\Phi$  is the work function (eV),  $E_{\text{vac}}$  is the electrostatic potential of vacuum level (eV), and  $E_f$  is the energy of Fermi level (eV).

The density of states (DOS) of the three  $\text{Cu}_2\text{O}$  nanocrystal facets were also calculated with an increased Monkhorst-Pack k-point mesh of  $3 \times 3 \times 1$ . The adsorption energy ( $E_{\text{ads}}$ ) of the adsorbate (i.e.,  $\text{H}_2\text{O}$  or  $[\text{Ru}(\text{NH}_3)_6]^{3+}$ ) is calculated by:

$$E_{\text{ads}} = E_{A/\text{surf}} - E_{\text{surf}} - E_{A(\text{g})} \quad (3)$$

where  $E_{A/\text{surf}}$ ,  $E_{\text{surf}}$  and  $E_{A(\text{g})}$  are the energy of the adsorbate molecules on the surface (eV), the energy of clean surface (eV), and the energy of isolated  $A$  molecule (eV) in a cubic periodic box with a side length of 20 Å and a  $1 \times 1 \times 1$  Monkhorst-Pack k-point grid for Brillouin zone sampling, respectively. The atomic charges were obtained from Bader charge calculations and analysis based on the numerical implementation developed by Henkelman et al. [46].

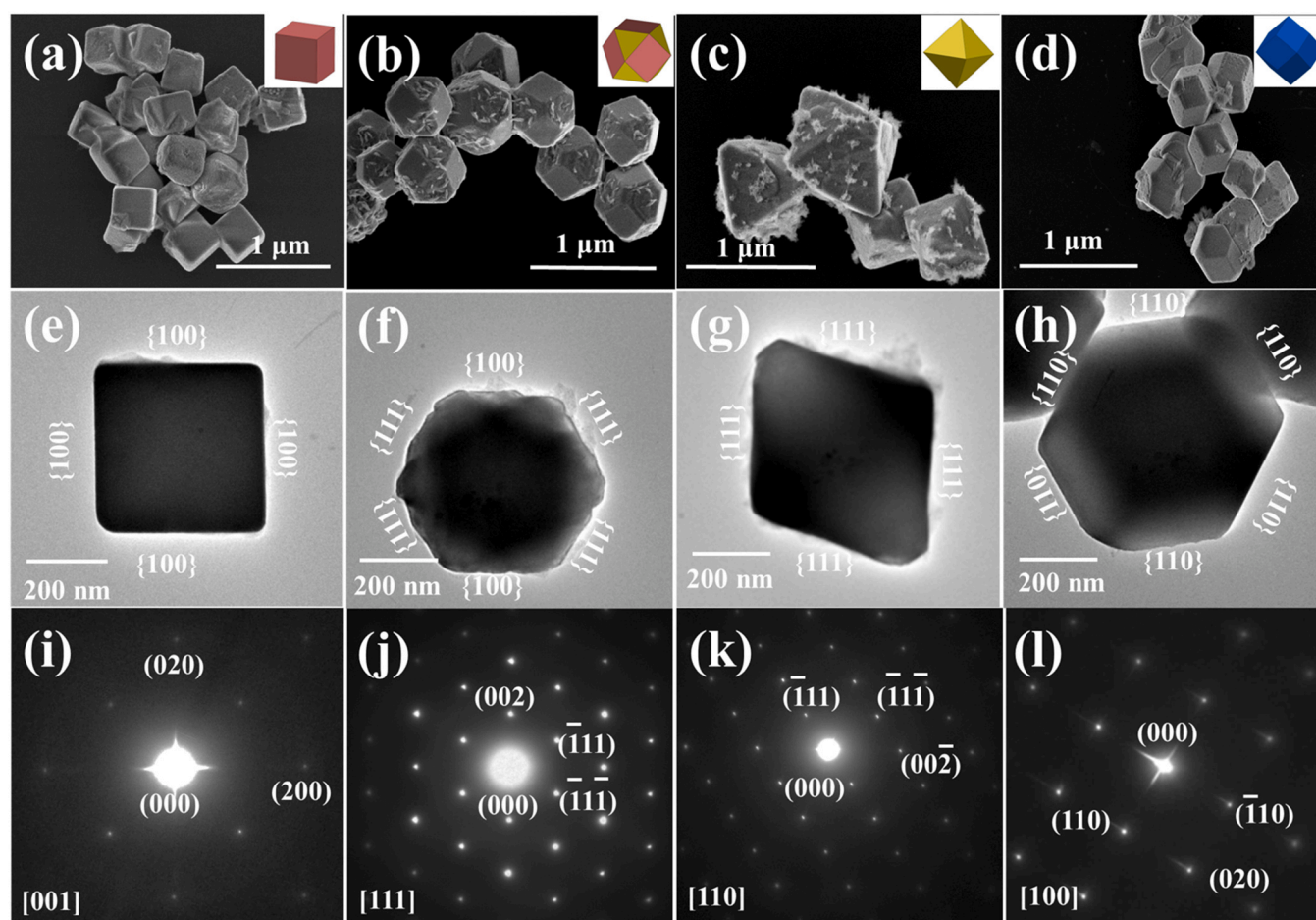
## Results and discussions

### Morphology and crystallographic facet indexing

The top panel of Fig. 1 shows high resolution SEM images of four different  $\text{Cu}_2\text{O}$  nanocrystals, which have comparable morphologies with previously reported results. [47] For example, cubic nanocrystals are generally composed of six identical square {100} facets. Cuboctahedron nanocrystals have six squares {100} facets in addition to the eight {111} facets. Octahedral nanocrystals are those with an octahedral structure bound by only {111} facets. There are twelve congruent rhombic {110} facets in a rhombic dodecahedron.

The insert of top row illustrates the 3-D models of the four shaped nanocrystals. The second row shows their typical TEM images. The third row shows SAED images. For a cubic particle made of six exposed {100} facets, when the electron beam was aligned to be perpendicular to the direction of the [001], a two-dimensional (2-D) square-shaped projection should be observed in the TEM image. Four facets in the {100} family, which are parallel to [001] zone axis,





**Fig. 1.** SEM images, sketch, bright TEM images and corresponding SAED patterns of the  $\text{Cu}_2\text{O}$  nanocrystals with various morphologies: cube, cuboctahedron, octahedron, and rhombic dodecahedron.

are marked in Fig. 1e. The HR-TEM images and the index of the spots in the SAED patterns indicate that this  $\text{Cu}_2\text{O}$  nanocrystal product is a single crystal and these cubes mainly have their {100} crystal facets exposed, which can also be evidenced by the XRD patterns (Fig. S8).

As for a cuboctahedron bounded by six square {100} and eight triangle {111} facets, when the electron beam is aligned to be perpendicular to [111], the TEM image exhibits as an equilateral hexagon projection constructed by the edges of {100} and {110}. The corresponding diffraction patterns in Fig. 1j and XRD pattern in Fig. S8 demonstrate the existence of {100} and {111} facets. The SAED pattern of  $\text{Cu}_2\text{O}$  cuboctahedron gives two sets of lattice fringes of 0.21 nm and 0.246 nm with an intersection angle of  $60^\circ$ . These lattice fringes correspond to the lattice fringe of the (111) and (002) planes of the  $\text{Cu}_2\text{O}$  structure respectively (JCPDS card No. 34–1354). [48].

For an octahedral particle in Fig. 1g, the projection is a parallelogram made of the projections of four {111} facets if the electron beam is in parallel with the [110] zone axis. The SAED pattern of  $\text{Cu}_2\text{O}$  octahedron gives two sets of lattice fringes of 0.246 nm with an intersection angle of  $60^\circ$ . These lattice fringes respectively correspond to the lattice fringe of the (111) and (111) planes of the  $\text{Cu}_2\text{O}$  structure (JCPDS card No. 34–1354), and XRD pattern (Fig. S8) further indicates that octahedral  $\text{Cu}_2\text{O}$  is composed of single crystals and these crystalline octahedrons mainly have their {111} crystal facets exposed.

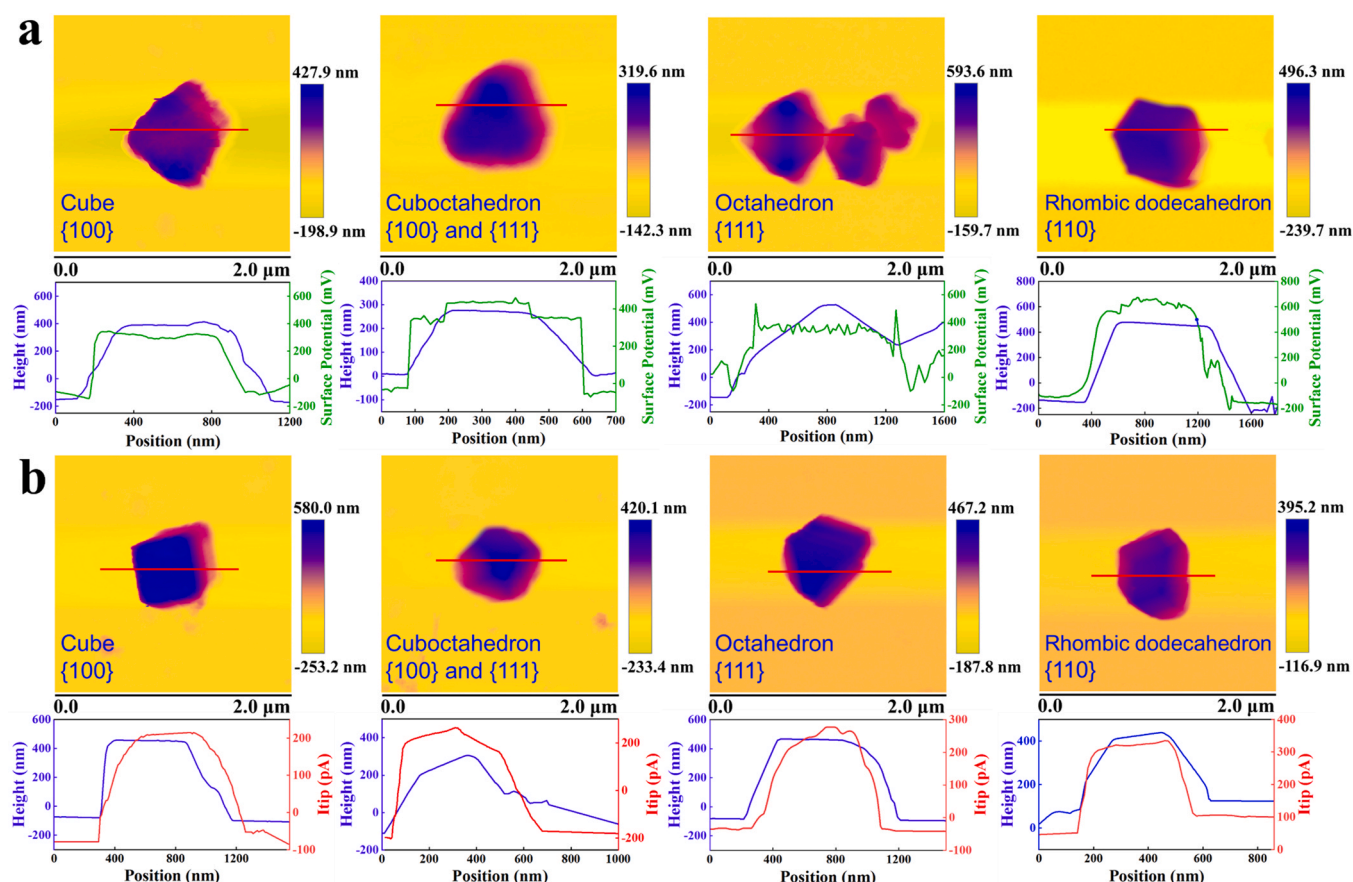
For a rhombic dodecahedron particle in Fig. 1h, the TEM projection is a hexagon shape if viewed from [110] zone axis. The six edges of the hexagon correspond to the edge of {110}. The lattice fringe of 0.30 nm of rhombic dodecahedron can be assigned to the

{110} plane of the  $\text{Cu}_2\text{O}$  structure. The SEAD pattern and XRD measurements reveal that rhombic dodecahedron mainly exposes the {110} facets of the single crystal.

#### Facet-Dependent Work Function

Work functions was measured by KPFM on single  $\text{Cu}_2\text{O}$  nanocrystals to reveal the different electronic structures of the {100}, {110}, and {111} facets. Fig. 2a shows the surface potential mapping of different  $\text{Cu}_2\text{O}$  nanocrystals deposited on the silicon wafer. Based on the analysis of over 15 different single nanocrystals for each shape, the surface potentials (or the CPD levels) are estimated to  $+320 \pm 50$ ,  $+350 \pm 70$ , and  $+400 \pm 58$  mV for the {100}, {110}, and {111} facet-dominant surfaces, respectively. The corresponding surface work function of {100}-cubic, {110}-rhombic dodecahedral, and {111}-octahedral  $\text{Cu}_2\text{O}$  are calculated to be 4.92, 4.95, and 5.00 eV, respectively. As previous study reported that the {100} and {110} facet surfaces of  $\text{Cu}_2\text{O}$  both had the lowest work functions, which supports our observation. [49] For the cuboctahedron  $\text{Cu}_2\text{O}$  nanocrystals, we observed a difference between {100} and {111} surfaces of  $\sim 80$  mV. This surface potential difference could, in turn, lead to the formation of an electronic surface junction or Schottky barrier that influences charge transfer across the solid interface. Compared with the {100} and {111} facets, the {110} facet possesses the intermediate electronic work function.

The DFT simulation results reveal that four  $\text{Cu}_2\text{O}$  nanocrystals elicit different surface structures and thus different work functions. For instance, the presence of highly electronegative atoms, such as



**Fig. 2.** (a) Morphology and cross-sectional surface potentials along the red lines in top images for four  $\text{Cu}_2\text{O}$  nanocrystals. (b) Typical topography and AFM-SECM cross-sectional tip-sample current along the red lines in top images for four  $\text{Cu}_2\text{O}$  nanocrystals.

**Table 1**

The calculated relaxed surface energies ( $\gamma_r$ ), work functions ( $\phi$ ), and the bandgaps ( $E_g$ ) of different  $\text{Cu}_2\text{O}$  surfaces, the bandgaps ( $E_g^*$ ) of the  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  adsorption on different  $\text{Cu}_2\text{O}$  surfaces, the adsorption energies ( $E_{\text{ads}}$ ) of the  $\text{H}_2\text{O}$  and  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  adsorption on different  $\text{Cu}_2\text{O}$  surfaces and the charge transfer between  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  cation and different  $\text{Cu}_2\text{O}$  surfaces.

Surface	$\gamma_r$ ( $\text{J}\cdot\text{m}^{-2}$ )	$\phi$ (eV)	$E_g$ (eV)	$E_g^*$ (eV)	$E_{\text{ads}}(\text{H}_2\text{O})$ (eV)	$E_{\text{ads}}([\text{Ru}(\text{NH}_3)_6]^{3+})$ (eV)	Charge transfer (e)
{100}:Cu	1.12	4.48	0.46	0.14	-1.28	-4.21	-0.76
{100}:O	1.05	5.58	0.97	0.56	-1.72	-4.86	-0.70
{110}:Cu	2.12	3.93	-	-	-2.95	-9.93	-1.11
{110}:Cu-O	2.09	5.66	-	-	-0.75	-4.44	-0.49
{111}:Cu	2.01	4.82	0.59	0.32	-1.77	-4.10	-0.58
{111}:O	1.87	4.67	0.49	0.45	-1.80	-4.59	-0.52

oxygen, at the surface increases the contribution of the dipole double layer to this electrostatic barrier, making it harder for an electron to leave the surface. As such, both the {100}:O and {110}:Cu-O structures were found to render significantly higher work functions than the only Cu-terminated surfaces. Conversely, the work function of the {110}:Cu structure is smallest in value when compared to that of other surfaces, which may result in the increased electron transfer. In addition, a comparison between the measured work function by KPFM in Fig. 2a and the DFT simulations in Table 1 shows that the calculated work functions of the {100}:O, the {110}:Cu-O, and the {111}:Cu are very close to the KPFM results. The minor discrepancies could result from the surface adsorption of water molecules present in the ambient air that forms a dipole layer and affects an effective surface potential.[50] The average DFT-computed work functions for each surface termination are, in

general, in agreement with the experimental measurements; however, the surface electronic structure of the three  $\text{Cu}_2\text{O}$  nanocrystal are too complex to be precisely modeled and calculated. The work function measurement indicates that  $\text{Cu}_2\text{O}$  nanocrystals also exhibit facet-dependent work functions, which may affect the interfacial charge transfer and the molecular interactions.[51] For example, the measured work function of {110}-rhombic dodecahedral is lower than that of {111}-octahedral  $\text{Cu}_2\text{O}$ . This result matches the first-principles calculations in adsorption energies ( $E_{\text{ads}}$ ) and charge transfer calculations.

#### Facet-dependent electrochemical activity

Local electronic structures could influence the solvent/electrolyte properties and double layer effects on surface electrochemical processes or reactions of  $\text{Cu}_2\text{O}$  nanocrystals. The topography and cross-sectional tip-sample current of four types of  $\text{Cu}_2\text{O}$  nanocrystals are compared in Fig. 2b. The tip current image contrast was generated due to the enhanced reduction reaction of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  to  $[\text{Ru}(\text{NH}_3)_6]^{2+}$  with a DC bias potential at -0.4 V applied to the tip, which has a tip radius of 25 nm and a tip height of 215 nm. As depicted in Fig. S2e, when the tip approached the sample surface, the tip current increased due to the enhanced oxidation reaction of  $[\text{Ru}(\text{NH}_3)_6]^{2+}$  at the  $\text{Cu}_2\text{O}$  surface under a positive DC bias (+0.1 V). The oxidized product then diffused to the tip for reductive reactions, which led to a higher tip current. In Section S2, we analyzed the effect of tip-sample distance on the measured tip current, which shows the concentration of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  at the tip surface decreased with the tip-sample distance. By contrast, the silicon substrate, though under the same positive DC bias, did not exhibit the same oxidative

reactivity toward  $\{\text{Ru}(\text{NH}_3)_6\}^{2+}$  and thus generated a relatively low tip current enhancement.

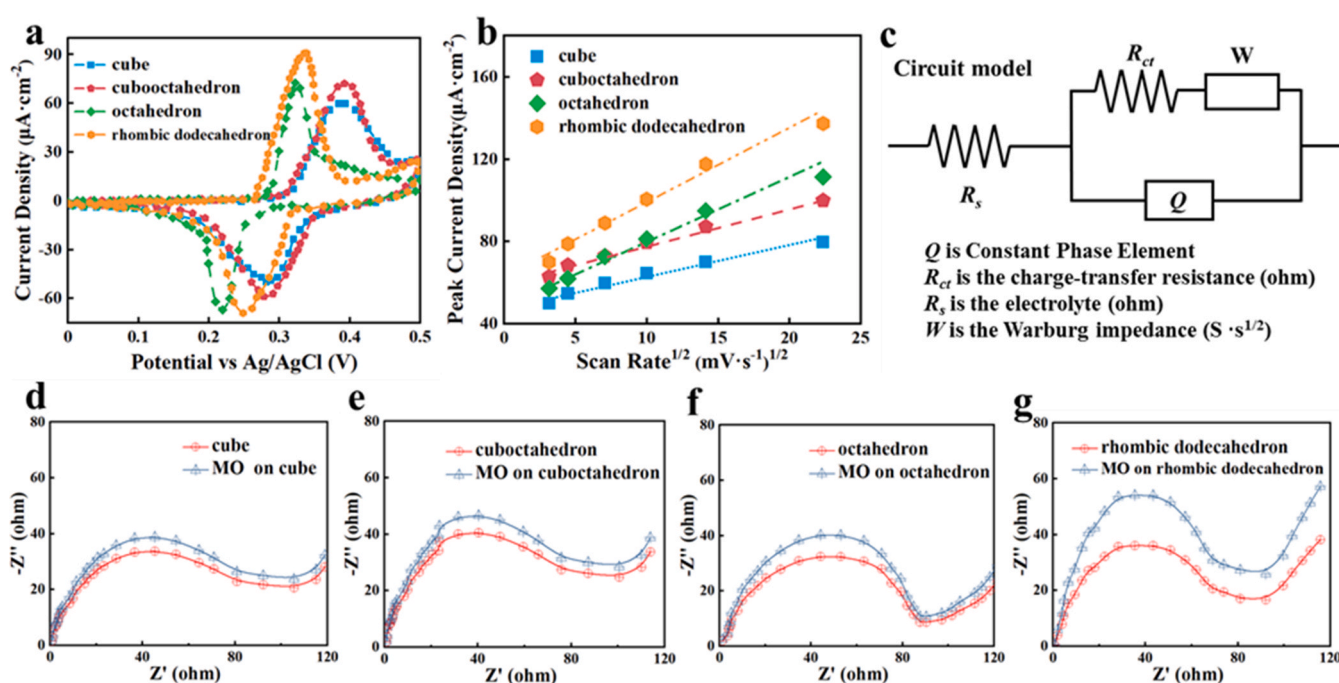
Furthermore, Fig. 2b shows that the tip-sample current exhibited slight dependence on the shape or exposed facets of  $\text{Cu}_2\text{O}$  nanocrystals. Cube, cuboctahedron, octahedron and rhombic dodecahedron of  $\text{Cu}_2\text{O}$  nanocrystals yielded an average tip current of  $205.4 \pm 16.4$ ,  $233.4 \pm 26.8$ ,  $279.4 \pm 25.2$  and  $318.3 \pm 17.8$  pA, respectively, at the same tip-sample distance of 100 nm. The observed shape dependence of tip currents supports our speculation of the effects of different facet surface states (e.g., work functions) on electrolyte/electrode interactions. For instance, the diffusion and concentration profile or distribution of the redox mediator from the bulk solution to the probe tip could be affected by the local interactions of mediator molecules and facet surfaces.[52] The interplay or overlapping of the two electric double layers of the samples and the probes affects the diffusion transport of the redox mediators and ultimately the redox reactions at the tip (or tip current). Fig. S2d shows that the tip captured a slightly higher effective surface concentration ( $C_d$ ) of the redox mediator when approaching the {110} facet of  $\text{Cu}_2\text{O}$  compared with {100} and {111} facets. This higher tip current resulted from the faster loop reaction rates of the redox mediators between the tip and the sample surface as illustrated Fig. S2e.

#### Traditional electrochemical activity assessment of $\text{Cu}_2\text{O}$ nanocrystals

Cyclic Voltammetry (CV) could potentially reveal the “fingerprint” of specific lattice planes of nanoparticles such as gold,[53]  $\text{CeO}_2$ [54] and  $\text{Co}_3\text{O}_4$ [55] For instance, the oxidation peak for {100} and {111} of gold nanostructures in 0.01 M aqueous  $\text{H}_2\text{SO}_4$  were reported to be +1.3 and +1.1 V (vs Ag/AgCl, saturated KCl), respectively.[56] To compare with the results from AFM/SECM, CV curves were obtained for the four types of  $\text{Cu}_2\text{O}$  nanocrystals as detailed in Section S3. Fig. 3a shows the typical CV curves that exhibit different peak currents at corresponding applied potentials. For  $\text{Cu}_2\text{O}$  nanocubes, a clear oxidation peak and a reduction peak is noted at around +0.38 V and +0.29 V (vs Ag/AgCl, 1.0 M KCl), respectively.  $\text{Cu}_2\text{O}$

nanocubes have a peak-to-peak potential separation or the difference between the oxidation and reduction peak potentials ( $\Delta E_p$ ) of 113 mV (vs. Ag/AgCl) with relatively low redox peak currents, due to the presence of the dominant {100} facets as shown in the HR-TEM results (Fig. 1i). For cuboctahedron, the CV peaks are determined by the {111} and {100} facets. The oxidation peak current of  $\text{Cu}_2\text{O}$  cuboctahedron is slightly higher than that of  $\text{Cu}_2\text{O}$  nanocubes, probably because the {111} plane of  $\text{Cu}_2\text{O}$  promoted the electron transfer or reactivity toward the probe molecules of  $[\text{Fe}(\text{CN})_6]^{3-/4-}$ . On the octahedron, a pair of well-defined redox peaks also appear with the  $\Delta E_p$  of 103 mV, due to the increase of the {111} plane. Similarly, rhombic dodecahedron achieved a lower  $\Delta E_p$  of 87 mV (vs. Ag/AgCl), indicating a higher charge-transfer ability and a more reversible electron transfer process on the electrode surface. The larger  $\Delta E_p$  values, the higher energy barrier present for the electron transfer and thus electrochemical reactions become more irreversible. Fig. S3 compares that for all the scan rate ( $\nu$ ) studied, the ratio of the cathodic and anodic processes' peak currents is consistently nearing 0.95, indicating the chemical reversibility as expected for the  $[\text{Fe}(\text{CN})_6]^{3-/4-}$  redox process. Furthermore, the Fig. 3b shows that from 10 to  $500 \text{ mV}\cdot\text{s}^{-1}$ , the peak currents density had a linear relationship with square root of scan rate ( $\nu^{1/2}$ ), demonstrating the classical Nernstian diffusion-controlled redox behavior.

Fig. 3d–g further compares the EIS complex-plane plots for the four types of  $\text{Cu}_2\text{O}$  nanocrystal-covered Au/Cu electrodes at an open-circuit potential in 5 mM  $\text{K}_3[\text{Fe}(\text{CN})_6]$  with 0.1 M KCl solution in the frequency range from 0.1 to  $10^6$  Hz. The semicircle portion at high frequencies characterizes the electron transfer limited process and the linear portion at lower frequencies results from a diffusion limited process. The distorted semicircle suggests that a double layer was established at the interface of electrolyte/ $\text{Cu}_2\text{O}$  nanocrystals on Au/Cu electrode. Smaller semicircle usually means faster interfacial charge transfer.[57] Moreover,  $\text{Cu}_2\text{O}$  nanocrystals-coated electrodes possessed smaller semicircle than that after methyl orange (MO) adsorption, which could increase the interfacial electric resistance. Details about MO adsorption on  $\text{Cu}_2\text{O}$  are provided in section S4.



**Fig. 3.** (a) Characteristic cyclic voltammetric curves of four  $\text{Cu}_2\text{O}$  nanocrystals under  $50 \text{ mV}\cdot\text{s}^{-1}$  scan rate ( $\nu$ ) in 5 mM  $\text{K}_3[\text{Fe}(\text{CN})_6]$  with 0.1 M KCl solution. (b) The peak current plots versus the square root of scan rates ( $\nu^{1/2}$ ) (from 10 to  $500 \text{ mV}\cdot\text{s}^{-1}$ ). (c) Equivalent circuit used to fit the Nyquist plots obtained via EIS. Nyquist impedance plots for the pristine  $\text{Cu}_2\text{O}$  nanocrystal-coated electrodes and those after methyl orange (MO)-adsorption: (d) cube, (e) cuboctahedra, (f) octahedra and (g) rhombic dodecahedra.



To quantify the interfacial resistance changes, the charge transfer resistance ( $R_{ct}$ ) was obtained by fitting the impedance data to an equivalent electric circuit model (Fig. 3c). Table S2 shows that  $R_{ct}$  increased from  $104.1 \pm 0.50 \Omega$  to  $112.2 \pm 0.36 \Omega$  before and after MO adsorption for the cubic  $\text{Cu}_2\text{O}$  nanocrystals. By contrast, upon deposition of cuboctahedron  $\text{Cu}_2\text{O}$  nanocrystals on the Au/Cu electrode, the  $R_{ct}$  value decreased to  $89.7 \pm 0.10 \Omega$ , indicating that the increased {111} facet facilitated electron transfer of the interfacial redox reactions.  $R_{ct}$  for the rhombic dodecahedron nanocrystal modified Au/Cu electrode further decreased to  $70.19 \pm 0.18 \Omega$  and achieved the faster electron transfer rate than cube, cuboctahedron and octahedron  $\text{Cu}_2\text{O}$ . This result matches the observed facet-dependent photocatalytic properties of  $\text{Cu}_2\text{O}$  nanocrystals, where rhombic dodecahedron with dominant {110} facets was reported to achieve greater efficiency of radical production, than octahedron and cube with dominant {111} and {100} facets respectively.[58,59] The range of  $n$  (0.85–0.96) for CPE further confirms that these electrode interface should be treated as an imperfect capacitor with non-ideal behavior of capacitance due to surface heterogeneity. Moreover, Table S2 shows that the relative change of  $R_{ct}$  before and after MO adsorption is different, suggesting different adsorption ability of MO for four different  $\text{Cu}_2\text{O}$  nanocrystals as supported by Fig. S4b.

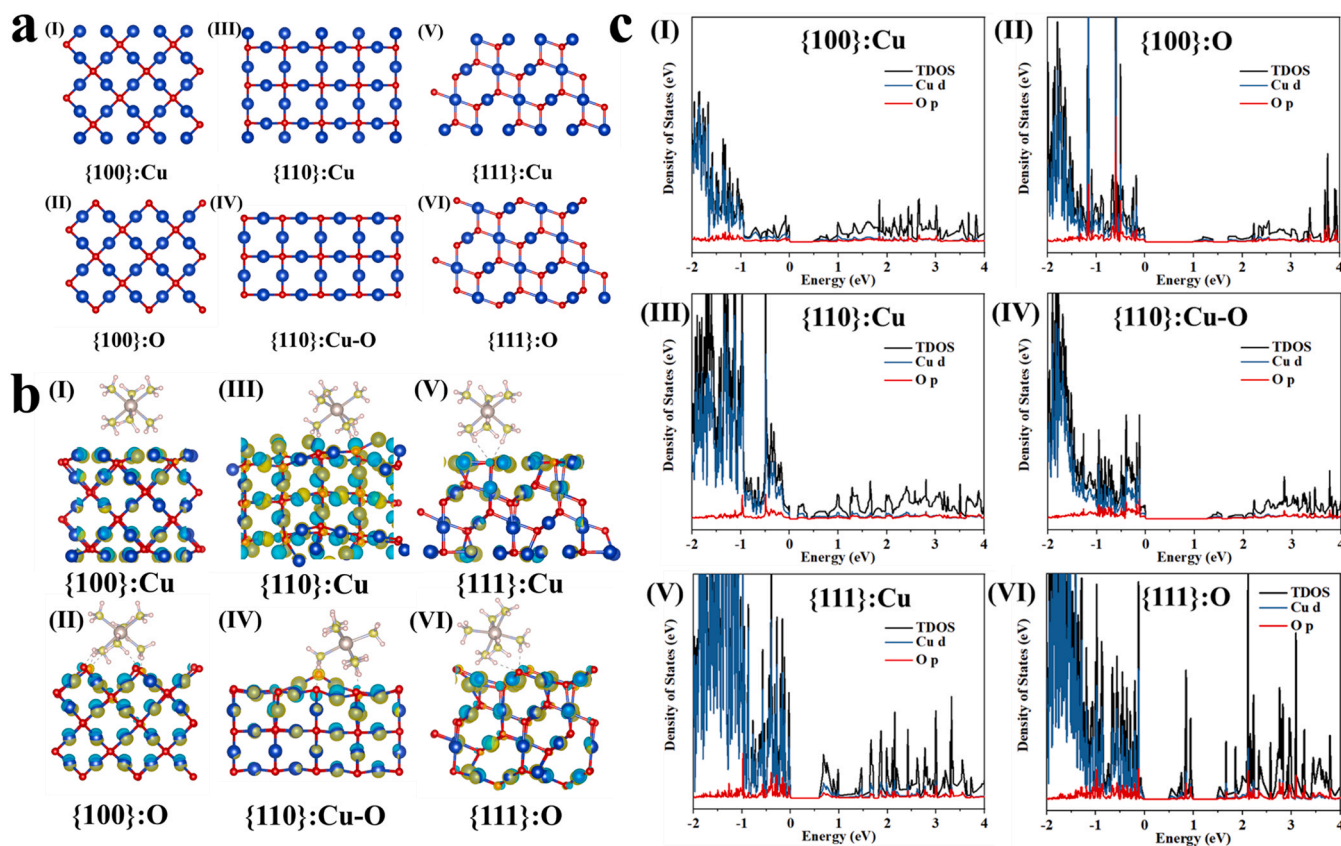
#### Mechanism analysis for facet-dependence of surface electronic and electrochemical properties

##### Surface energy and adsorption energy

We have calculated the surface energies of the six different surface terminations as shown in Table 1. First, the three low-index  $\text{Cu}_2\text{O}$  surfaces: {100}, {110} and {111}, were constructed with each

terminated in two ways as illustrated in Fig. 4a. The surface energy of {100}:Cu and the {100}:O are similar ( $1.12$  and  $1.05 \text{ J}\cdot\text{m}^{-2}$ , respectively). Only O atoms are terminated in the {100}:O facet, which has a slightly lower surface energy than the Cu terminated facet. The {110}:Cu and {110}:Cu–O have the highest surface energies of  $2.12$  and  $2.09 \text{ J}\cdot\text{m}^{-2}$  respectively. Finally, we found a surface energy of  $1.87 \text{ J}\cdot\text{m}^{-2}$  for the {111}:O surface that is slightly lower than that of {111}:Cu ( $2.01 \text{ J}\cdot\text{m}^{-2}$ ). Clearly, surface energy increases with the increase of under-coordinated Cu atoms as reported previously.[60] This {111}:O surface contains both doubly coordinated Cu atoms and undercoordinated, singly coordinated Cu atoms, with dangling bonds perpendicular to the surface. The {111}:Cu surface similarly exposes both Cu atoms and O atoms, but the density of dangling bonds is much less than the {110} surface. The surface energies of  $\text{Cu}_2\text{O}$  generally follow the density of undercoordinated Cu atoms,  $\{100\} < \{111\} < \{110\}$ . [61] A higher surface energy typically indicates a more reactive surface[62] and therefore the highest surface energy of each facet correlates with the observed adsorptive performance of the  $\text{Cu}_2\text{O}$  nanocrystals, as measured on the cubic {100} crystals, octahedral {111} crystals, and rhombic dodecahedral {110} crystals.

Adsorption energies of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  on the  $\text{Cu}_2\text{O}$  {100}, {110} and {111} surfaces are compared to explain and support the facet-dependent electrochemical reactivity. Fig. S5 shows the most stable adsorption configurations with different surface atomic bonding. The adsorption energies ( $E_{\text{ads}}$ ) of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  on all of the three crystal facets were negative, suggesting the adsorption processes could be exothermic and spontaneous. The adsorption energy,  $E_{\text{ads}}$ , correlates strongly with the surface energy ( $\gamma_r$ ), as shown in Table 1. For both adsorbates ( $\text{H}_2\text{O}$  and  $[\text{Ru}(\text{NH}_3)_6]^{3+}$ ), the {110} surface shows the strongest average adsorption energy, in agreement with the measured electrochemical activity.



**Fig. 4.** (a) Relaxed  $\text{Cu}_2\text{O}$  surfaces. (b) Three dimensional charge density difference maps of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  cation on  $\text{Cu}_2\text{O}$  surfaces (yellow: electron accumulation; cyan: electron depletion) Blue, red, gray, light blue, pink balls indicate Cu, O, Ru, N and H atoms, respectively. (c) Electronic DOS of  $\text{Cu}_2\text{O}$  surfaces.

### Bader charge analysis

To further investigate the electronic interactions between  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  and different crystal facets of  $\text{Cu}_2\text{O}$ , the charge transfer was also assessed for the adsorption of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  and summarized listed in Table 1. Fig. 4b shows that there is obvious electron injection from different  $\text{Cu}_2\text{O}$  surfaces to  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  cation as indicated that all N atoms are surrounded by yellow lobes that represent charge accumulation. The more charge transfer between  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  and these surfaces, the stronger the electronic interactions that form, which will lead to better catalytic activity. Thus, the  $\{110\}:\text{Cu}$  facets yielded a greater strength of electronic interaction with  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  than other facets,  $\{100\}$  facets and  $\{111\}$  facets as indicated by the lower charge transfer. The results explain the distinct reaction rates of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  on different  $\text{Cu}_2\text{O}$  facets.

### Density of states analysis

The calculated projected density of states (DOS) shows that both valence band maxima (VBM) and conduction band minima (CBM) mainly consist of O (p) and Cu (d) orbitals, respectively, while contributions from other orbitals are much less. The electronic band gaps ( $E_g$ ) of the three low-index  $\text{Cu}_2\text{O}$  surfaces with different surfaces terminations are determined from the (DOS) as the difference between the valence band maximum (VBM) and conduction band minimum (CBM), and are summarized in Table 1.

Fig. 4c shows that for  $\{100\}:\text{Cu}$  there is a small band gap of 0.46 eV, while the  $\{100\}:\text{O}$  surface shows a much larger band gap of 0.97 eV. We observed a finite number of states near the Fermi level in the electronic DOS of the  $\{110\}:\text{Cu}$  and  $\{110\}:\text{CuO}$  surfaces and hence propose that these surfaces are conducting. We also found that the bandgaps for the  $\{111\}$  surfaces are quite low; the  $\{111\}:\text{Cu}$  and  $\{111\}:\text{O}$  terminated surfaces are found to have band gaps of 0.59 eV and 0.49 eV, respectively. These results are in agreement with Soon et al., who employed the technique of “ab initio atomistic thermodynamics” to identify the surface structures of the  $\{110\}$  and  $\{111\}$  planes under oxygen-rich and oxygen-lean conditions.[37] Comparing the appropriate surfaces from that work with ours, we find agreement for the  $\{110\}$  and  $\{111\}$  cases; furthermore, their study indicated that these states are true metallic surface states. These metallic states at the Fermi level should make electron transfer more facile on the  $\{110\}$  surface compared to the  $\{111\}$  or  $\{100\}$ , further explaining the observed enhanced activity.

Finally, comparison of the bandgaps before and after adsorption of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  on  $\text{Cu}_2\text{O}$  surfaces suggests that the adsorption of  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  could narrow the bandgap mainly due to the presence of the N (p) impurity state as shown in the DOS of each  $\text{Cu}_2\text{O}$  surface after  $[\text{Ru}(\text{NH}_3)_6]^{3+}$  adsorption (Fig. S7). This N (p) impurity alter the band structure and the corresponding DOS of all  $\text{Cu}_2\text{O}$  surfaces and also facilitate charge transfer for each surfaces.

### Conclusion

With different facets exposing different surface atoms, tuning  $\text{Cu}_2\text{O}$  morphology correspondingly controls its surface chemistry and reactivity. Depending on the atomic coordination and structural configuration of  $\text{Cu}_2\text{O}$  surfaces, different proportions of cations and anions are accessible for molecular adsorption or reactions. Furthermore, different atomic coordination results in intrinsic properties such as distinct electron density configurations and band gap energies or structures, which also influence the type and strength of molecular interactions on facets. Because these electronic and molecular interaction characteristics govern the mechanisms in heterogeneous catalysis, gas sensing, or electrochemical reactions, the facet control or engineering holds paramount importance in functional nanomaterial synthesis and applications.

In this work, for the first time, KPFM and AFM-SECM demonstrated the nanoscale facet dependent electronic and

electrochemical properties of  $\text{Cu}_2\text{O}$  nanocrystals with different exposed facets. We employed traditional electrochemical measurement including cyclic voltammetry and electrochemical impedance spectroscopy to confirm facet dependent electrochemical properties of  $\text{Cu}_2\text{O}$  nanocrystals. Lastly, DFT calculations revealed that the higher surface energy and efficient electron transfer on  $\{110\}$  facet responsible for the higher electrochemical responses. The AFM-SECM technique should be applicable in the study of other electrochemical systems. Because it is based on a scanning-probe platform, the technique is suited for understanding heterogeneity in surface or interface electrochemical response (although not fully exploited in this work, our preliminary results indicate that this is possible). The technique could also provide insight into understanding the operation of batteries, fuel cells and other electrochemical systems.

### CRediT authorship contribution statement

**Qingquan Ma:** Methodology, investigation and writing original draft preparation, **Joshua Young:** Supervision, writing, reviewing and editing, **Sagnik Basuray:** Reviewing and editing, **Guangming Cheng:** TEM analysis and writing, **Jianan Gao:** TOC design and data analysis, **Nan Yao:** Reviewing and editing, **Wen Zhang:** Supervision, Conceptualization, writing, reviewing and editing.

### Data Availability

Data will be made available on request.

### Declaration of Competing Interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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### Appendix A. Supporting information

Supplementary data associated with this article can be found in the online version at doi:10.1016/j.nantod.2022.101538.

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